

## Data Sheet

### Description

Avago Technologies' MGA-631P8 is an economical, easy-to-use GaAs MMIC Low Noise Amplifier (LNA) with active bias. The LNA has low noise with excellent input return loss and high linearity achieved through the use of Avago Technologies' proprietary 0.5um GaAs Enhancement-mode pHEMT process. The LNA has an extra feature that allows a designer to adjust supply current and gain externally. Due to the high isolation between the input and output, gain can be adjusted independently through a resistor in series with a blocking capacitor from the output pin to FB1 pin, without affecting the noise figure. It is housed in a miniature 2.0 x 2.0 x 0.75mm<sup>3</sup> 8-pin Thin Small Leadless Package (TSLP) package. The compact footprint and low profile coupled with low noise, high gain, excellent input return loss and high linearity make the MGA-631P8 an ideal choice as an LNA for cellular infrastructure for GSM, CDMA, GPS and ISM applications.

It is designed for optimum use between 400MHz to 1.5GHz. For optimum performance at higher frequency from 1.4GHz to 3.8GHz, the MGA-632P8 is recommended. Both MGA-631P8 and MGA-632P8 share the same package and pinout.

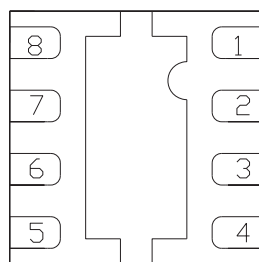
### Pin Configuration and Package Marking

2.0 x 2.0 x 0.75 mm<sup>3</sup> 8-lead TSLP



#### Top View

Note:  
Package marking provides orientation and identification  
"G1" is Device Code  
"X" is month code



#### Bottom View

Note:  
Pin 1 : not used      Pin 5 : FB1  
Pin 2 : RFin          Pin 6 : not used  
Pin 3 : RF ground    Pin 7 : RFout  
Pin 4 : Vbias         Pin 8 : Gnd

### Features

- Low noise figure
- Good input return loss
- High linearity performance
- High Isolation
- Externally adjustable supply current, 40-80mA
- Externally adjustable gain, 15-20dB
- GaAs E-pHEMT Technology<sup>[1]</sup>
- Low cost small package size: 2.0x2.0x0.75 mm<sup>3</sup>
- Excellent uniformity in product specifications

### Specifications

900MHz; 4V, 54mA (typ)

- 17.5 dB Gain
- 0.53 dB Noise Figure
- -19.4dB S11
- -34dB S12
- 32.6 dBm Output IP3
- 18.0 dBm Output Power at 1dB gain compression

### Applications

- Low noise amplifier for cellular infrastructure for GSM, CDMA, GPS and ISM.
- Other ultra low noise applications.

Note:

1. Enhancement mode technology employs positive Vgs, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.



**Attention: Observe precautions for handling electrostatic sensitive devices.**

ESD Machine Model = 50 V  
ESD Human Body Model = 200 V  
Refer to Avago Application Note A004R:  
*Electrostatic Discharge, Damage and Control.*

## MGA-631P8 Absolute Maximum Rating [1]

Symbol	Parameter	Units	Absolute Max.
Vd	Device Supply Voltage	V	5.5
P <sub>in,max</sub>	CW RF Input Power (Vd=4.0V, Vbias=4.0V)	dBm	20
P <sub>diss</sub>	Total Power Dissipation [2]	W	0.55
T <sub>j</sub>	Junction Temperature	°C	150
T <sub>STG</sub>	Storage Temperature	°C	-65 to 150

**Thermal Resistance [3]** (Vd = 4.0V, Vbias=4.0V),  $\theta_{JC} = 47 \text{ }^\circ\text{C/W}$

Notes:

1. Operation of this device in excess of any of these limits may cause permanent damage.
2. Board temperature T<sub>B</sub> is 25 °C. Derate 21.2mW/ °C for T<sub>B</sub>>124 °C.
3. Thermal resistance measured using Infra-Red Microscopy Technique.

## Product Consistency Distribution Charts [4]

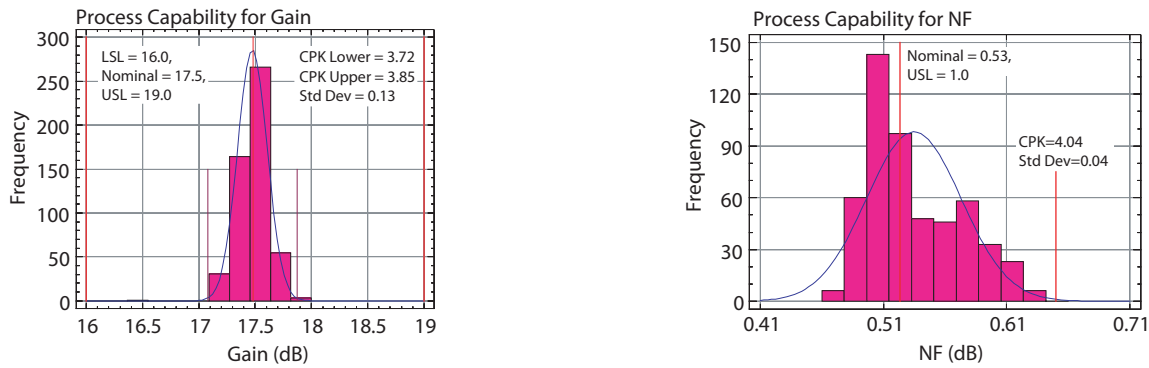


Figure 1. Gain distribution at 54mA

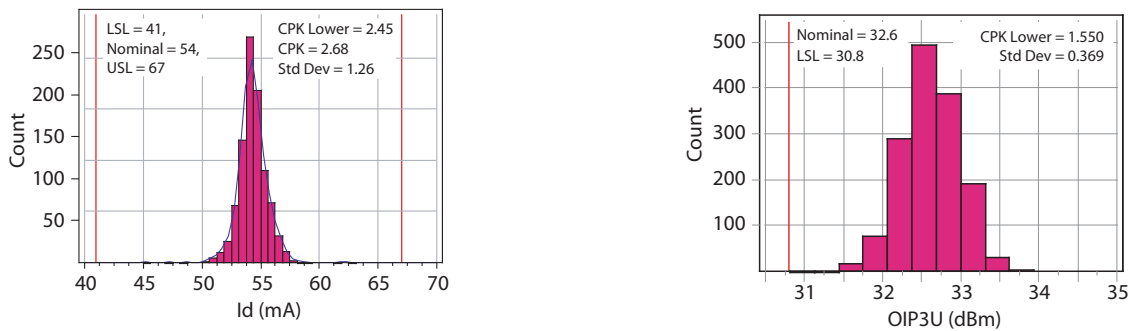


Figure 3. Id distribution at 54mA

Figure 4. OIP3U distribution at 54mA

4. Distribution data sample size is 500 samples taken from 3 different wafer lots. Future wafer allocated to this product may have nominal values anywhere between the upper and lower limits. Circuit losses have been de-embedded from actual measurements.

## Electrical Specifications [1,2]

$T_A = 25\text{ }^\circ\text{C}$ ,  $V_d = 4\text{V}$  @  $54\text{mA}$ ,  $R_1 = 91\text{ohm}$  unless otherwise specified.

Symbol	Parameter and Test Condition		Units	Min.	Typ.	Max.
Id	Operational Current	Vbias=4.0V	mA	41	54	67
Gain	Freq=800 MHz	Associated Gain	dB	16.0	18.4	19.0
	Freq=850 MHz				17.9	
	Freq=900 MHz				17.5	
OIP3	Freq=800 MHz	Output Third Order Intercept Point (2-tone @ $F_{RF} \pm 5\text{MHz}$ , $P_{in} = -20\text{dBm}$ )	dBm	30.8	34.2	32.6
	Freq=850 MHz				33.8	
	Freq=900 MHz				32.6	
NF <sub>50Ω</sub>	Freq=800 MHz	Noise Figure in 50Ω system	dB		0.57	1.0
	Freq=850 MHz				0.51	
	Freq=900 MHz				0.53	
OP1dB	Freq=800 MHz	Output Power at 1dB Gain Compression	dBm		18.3	18.0
	Freq=850 MHz				18.0	
	Freq=900 MHz				18.0	
IRL	Freq=800 MHz	Input Return Loss	dB		-20.9	-19.4
	Freq=850 MHz				-30.6	
	Freq=900 MHz				-19.4	
ORL	Freq=800 MHz	Output Return Loss	dB		-21.3	-22.5
	Freq=850 MHz				-22.1	
	Freq=900 MHz				-22.5	
S12	Freq=800 MHz	Reverse Isolation	dB		-34.0	-34.0
	Freq=850 MHz				-34.0	
	Freq=900 MHz				-34.0	

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1. Input and output board losses have been de-embedded.
2. Guaranteed specifications are 100% tested in production test circuit.

## Typical Electrical Specifications at 700MHz [3]

$T_A = 25\text{ }^\circ\text{C}$ ,  $V_d = 4\text{V}$  @  $54\text{mA}$ ,  $R_1 = 91\text{ohm}$  unless otherwise specified.

Symbol	Parameter and Test Condition		Units	Typ.
Gain	Freq=700MHz	Associated Gain	dB	17.1
OIP3	Freq=700MHz	Output Third Order Intercept Point (2-tone @ $F_{RF} \pm 5\text{MHz}$ , $P_{in} = -20\text{dBm}$ )	dBm	35.7
NF <sub>50Ω</sub>	Freq=700MHz	Noise Figure in 50Ω system	dB	1.12
OP1dB	Freq=700MHz	Output Power at 1dB Gain Compression	dBm	15.1
IRL	Freq=700MHz	Input Return Loss	dB	-12.1
ORL	Freq=700MHz	Output Return Loss	dB	-3.2
S12	Freq=700MHz	Reverse Isolation	dB	-38.4

Notes:

3. Measurements obtained using demo board described in Figure 28 and Table 1, List 4. Input and output board losses have been de-embedded.

# MGA-631P8 Typical Performance<sup>[1]</sup>

T<sub>A</sub> = 25 °C, V<sub>d</sub> = 4V, I<sub>d</sub> = 54mA, R<sub>1</sub>=91ohm unless stated otherwise.

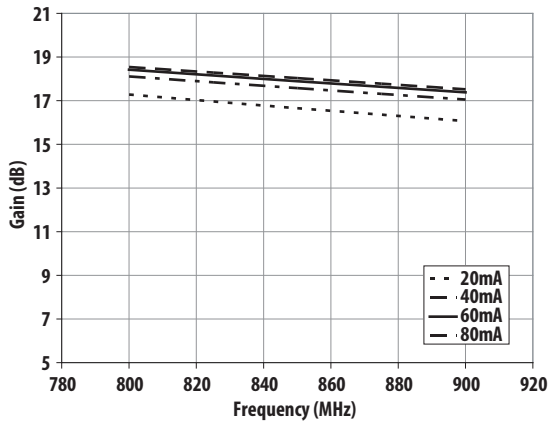


Figure 5. Gain Vs Frequency and Id

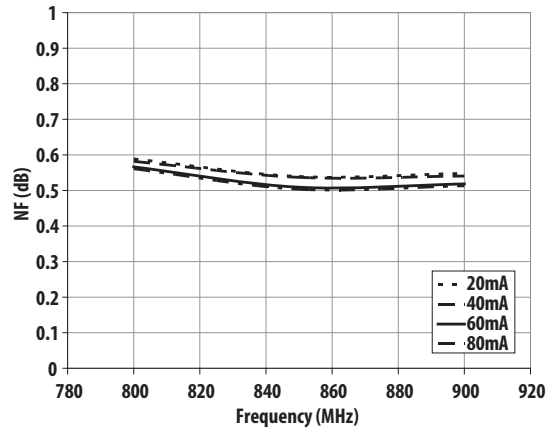


Figure 6. NF Vs Frequency and Id

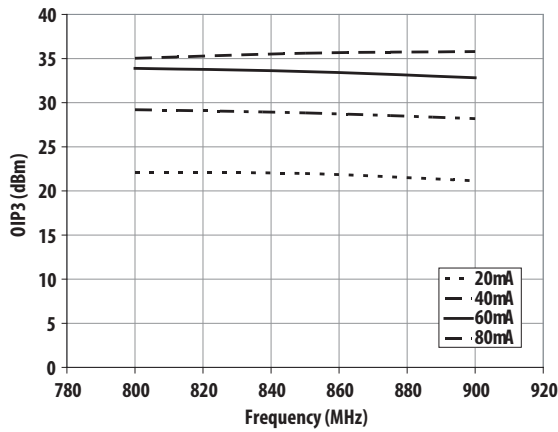


Figure 7. OIP3 Vs Frequency and Id

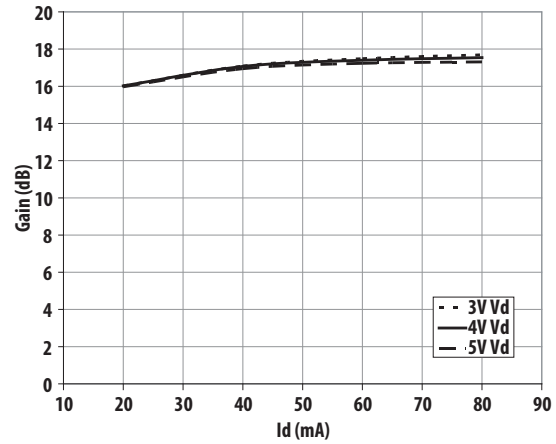


Figure 8. Gain Vs Id and Vd

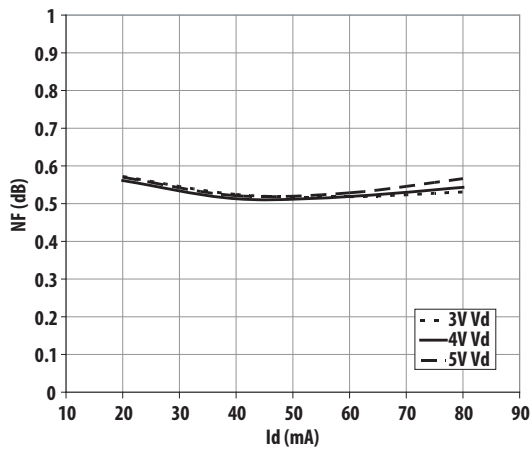


Figure 9. NF Vs Id and Vd

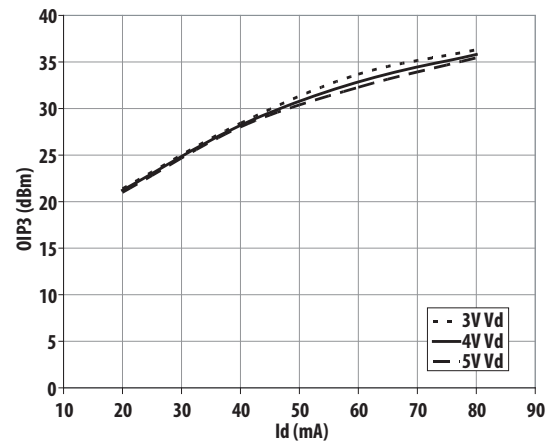


Figure 10. OIP3 Vs Id and Vd

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1.

# MGA-631P8 Typical Performance<sup>[1]</sup>

T<sub>A</sub> = 25 °C, V<sub>d</sub> = 4V, I<sub>d</sub> = 54mA, R<sub>1</sub>=91ohm unless stated otherwise.

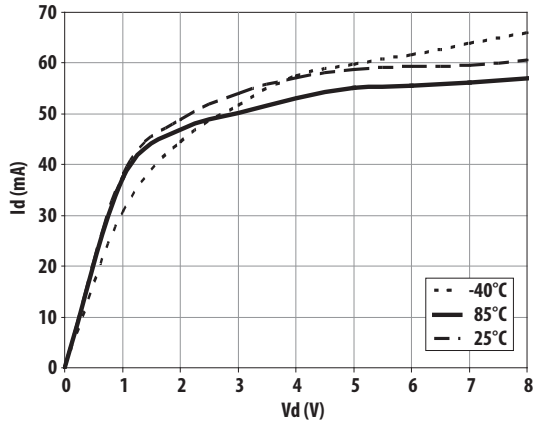


Figure 11. Id Vs Vd and Temperature

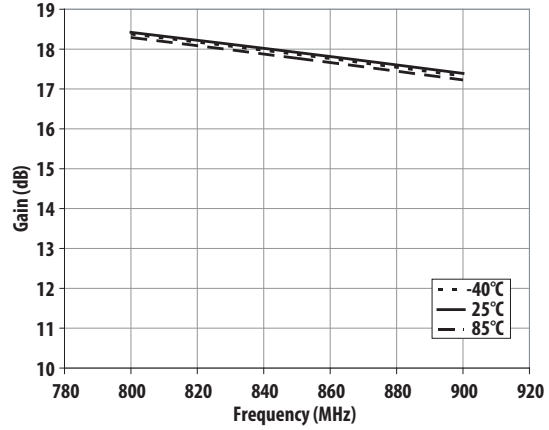


Figure 12. Gain Vs Frequency and Temperature

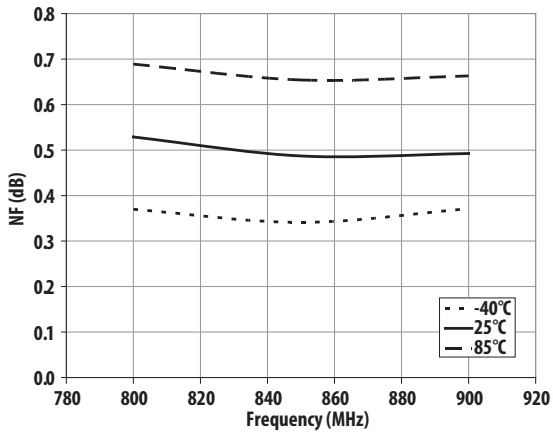


Figure 13. NF Vs Frequency and Temperature

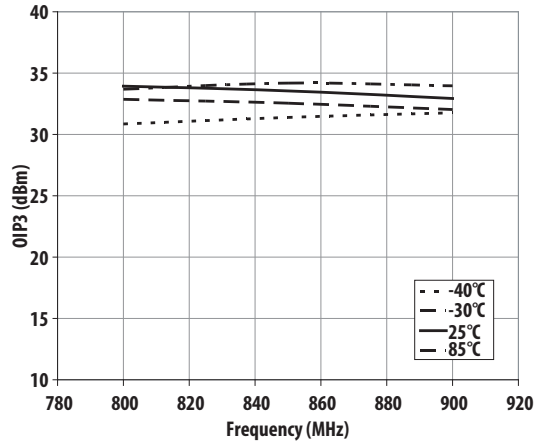


Figure 14. OIP3 vs Frequency and Temperature

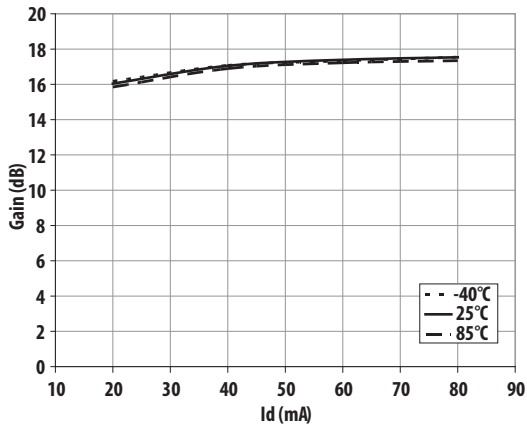


Figure 15. Gain vs Id and Temperature

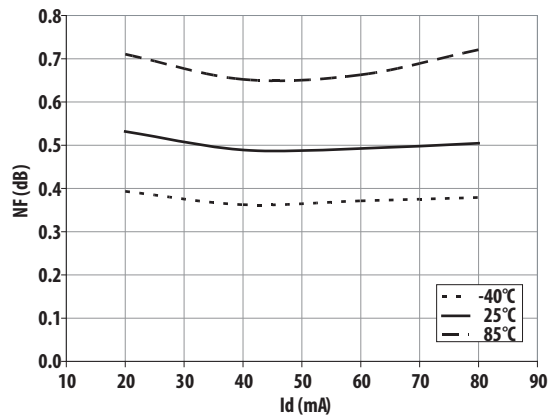


Figure 16. NF Vs Id and Temperature

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1.

# MGA-631P8 Typical Performance<sup>[1]</sup>

T<sub>A</sub> = 25 °C, V<sub>d</sub> = 4V, I<sub>d</sub> = 54mA, R1=91ohm unless stated otherwise.

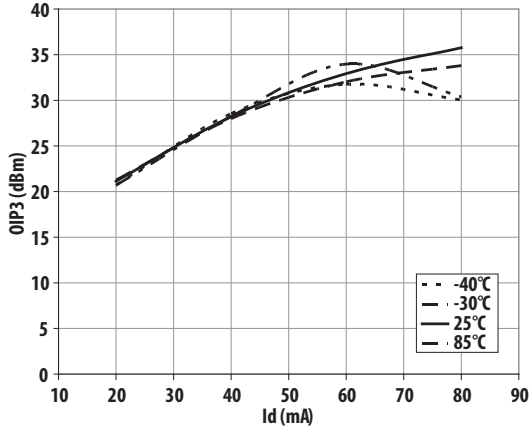


Figure 17. OIP3 vs Id and Temperature

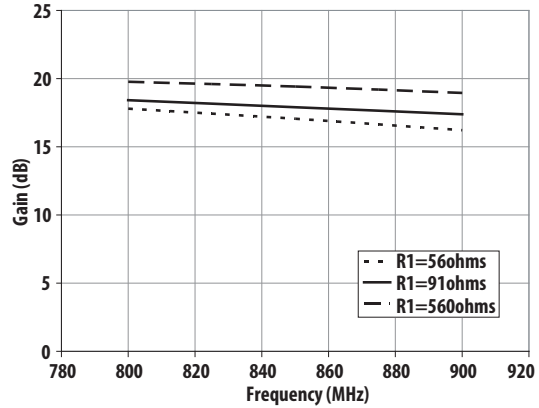


Figure 18. Gain Vs Frequency and R1

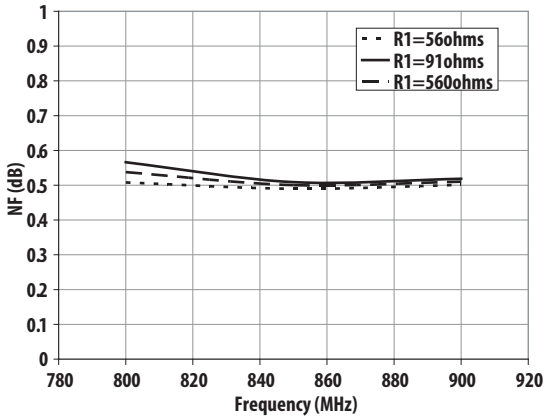


Figure 19. NF Vs Frequency and R1

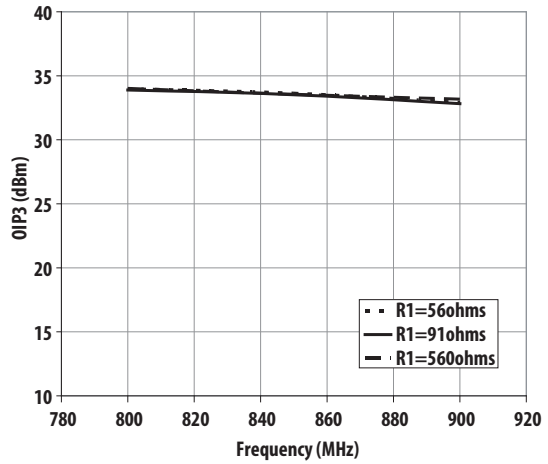


Figure 20. OIP3 Vs Frequency and R1

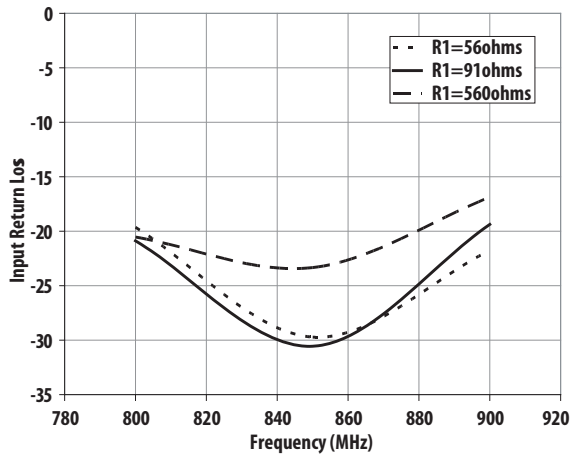


Figure 21. Input Return Loss Vs Frequency and R1

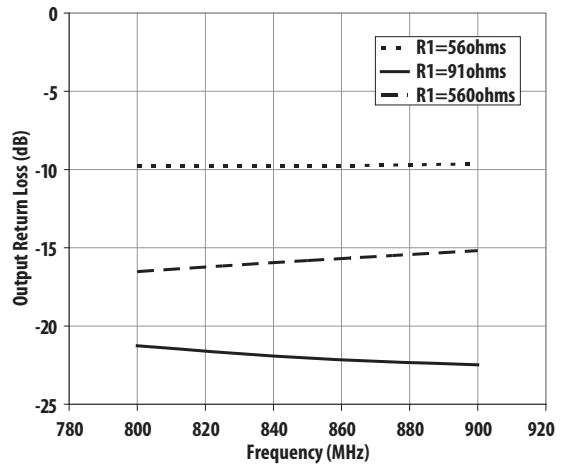


Figure 22. Output Return Loss Vs Frequency and R1

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1.

### MGA-631P8 Typical Performance for 450 Mz Matching [1]

$T_A = +25\text{ }^\circ\text{C}$ ,  $V_d = 4\text{V}$ ,  $I_d = 54\text{mA}$

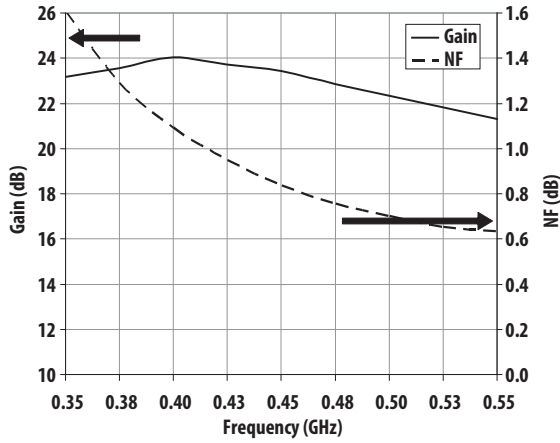


Figure 23. Gain and NF Vs Frequency

### MGA-631P8 Typical Performance for 1.5 GHz Matching [2]

$T_A = +25\text{ }^\circ\text{C}$ ,  $V_d = 4\text{V}$ ,  $I_d = 54\text{mA}$

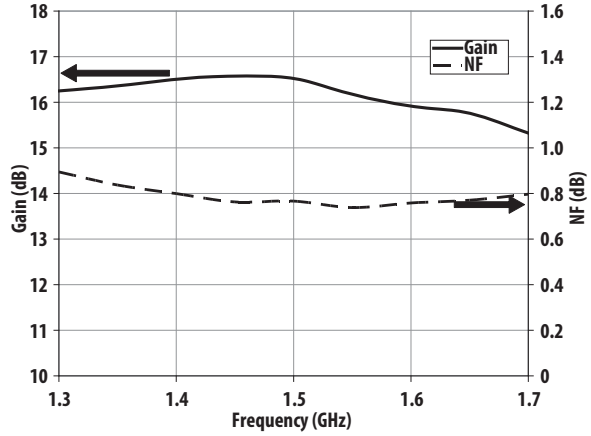


Figure 26. Gain and NF vs Frequency

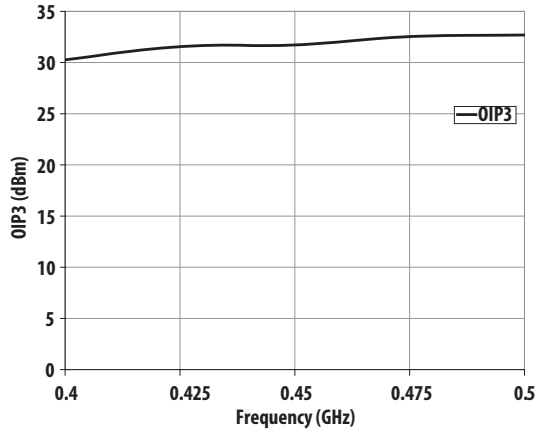


Figure 24. OIP3 vs Frequency

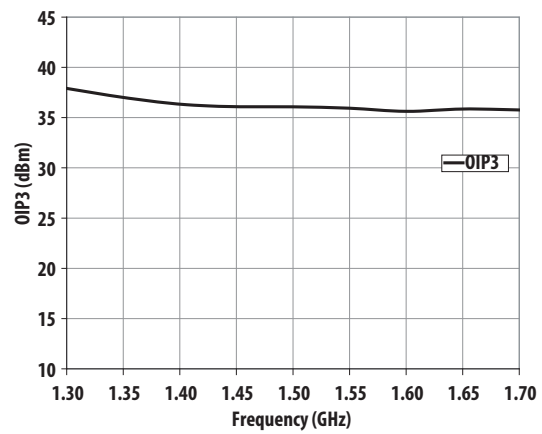


Figure 27. OIP3 vs Frequency

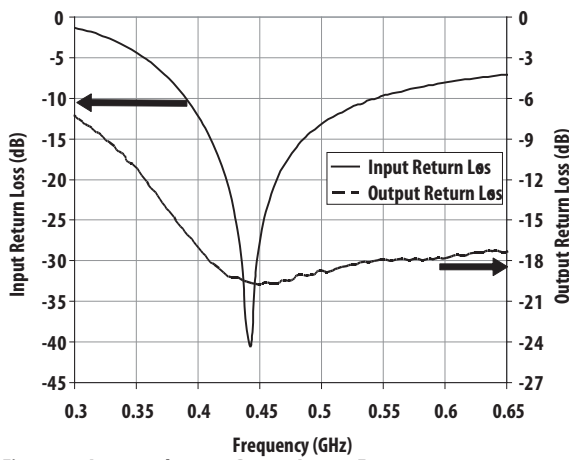


Figure 25. Input and output Return Loss vs Frequency

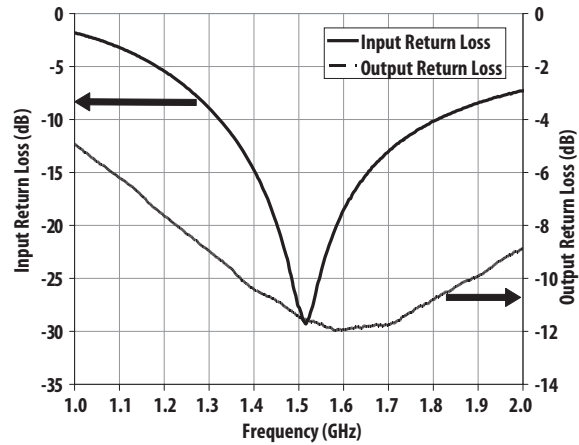


Figure 28. Input and output Return Loss vs Frequency

Notes:

1. For Figure 22, 23 and 24, measurements obtained using demo board described in Figure28 and Table 1, List 2.
2. For Figure 25, 26 and 27, measurements obtained using demo board described in Figure28 and Table 1, List 3.

## Demo Board Layout

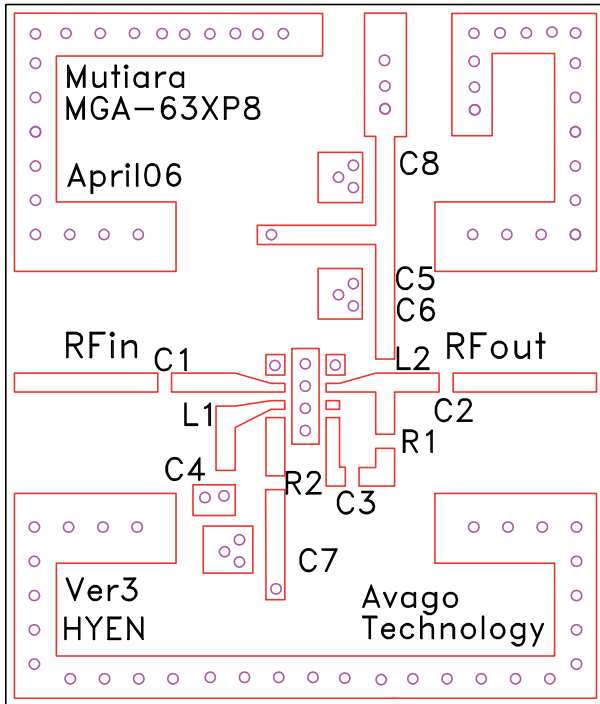


Figure 29. Demo Board Layout Diagram

- Recommended PCB material is 10 mils Rogers RO4350.
- Suggested component values may vary according to layout and PCB material.

## Demo Board Schematic for Table 1, List 1 (900 MHz Matching) and List 2 (450 MHz Matching).

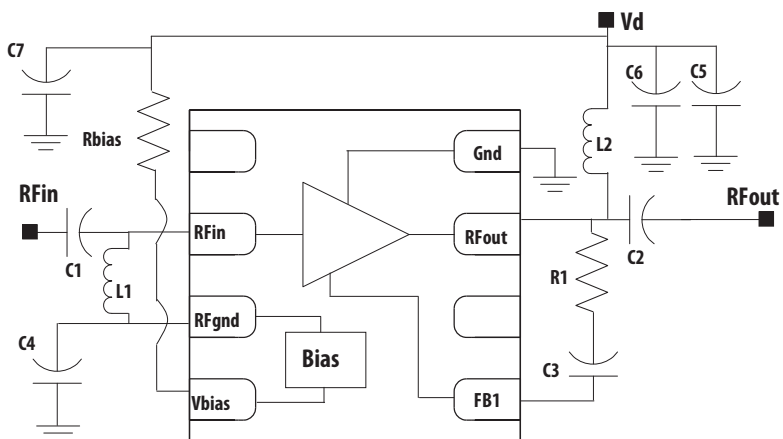


Figure 30. Demo Board Schematic.

Note: This demo board is used for measuring Electrical Specifications and plots of Fig. 4 to Fig. 24. Table 1, List 1 shows the components values used while measuring Fig. 4 to Fig. 21. Table 1, List 2 shows the components values used while measuring Fig. 22 to Fig. 24.



### Demo Board Schematic for Table 1, List 3 (1.5 GHz Matching)

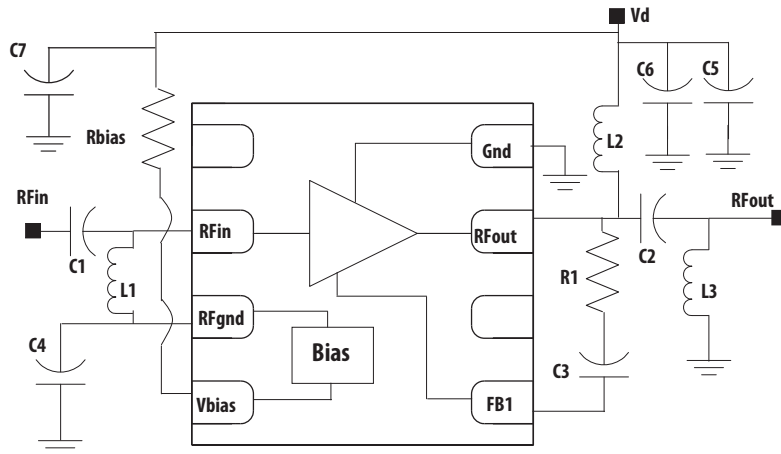


Figure 31. Demo Board Schematic with additional shunt inductor, L3, at RFout. This demo board is used for measuring plots of Fig. 25 to Fig. 27. Table1, List 3 shows the components values.

### Demo Board Schematic for Table 1, List 4 (700MHz Matching)

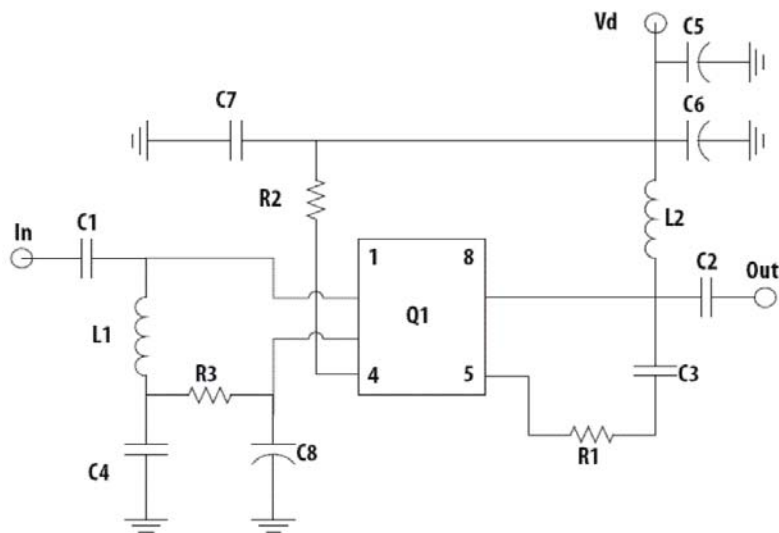


Figure 32. Demo Board Schematic with additional C8 and R3. Table 1, List4 shows the component values.

**Table 1**

- List 1 – Demo board component values for Demo board Schematic of Fig. 29.  
These component values are used when measuring Electrical Specifications and plots of Fig. 4 to Fig. 21.
- List 2 – Demo Board Component values for Demo board Schematic of Fig. 29.  
These component values are used while measuring plots of Fig. 22 to Fig. 24.
- List 3 – Demo Board Component values for Demo board Schematic of Fig. 30.  
These component values are used while measuring plots of Fig. 25 to Fig. 27.
- List 4 – Demo Board Component values for Demo board Schematic of Figure 31.

Part	Size	List 1 (900 MHz Matching)	List 2 (450 MHz Matching)	List 3 (1.5 GHz Matching)	List 4 (700MHz Matching)
L1	0402	13.0nH (Coilcraft 0402CS-13NXJBW)	27.0nH (Toko LL1005-FHL27NS)	4.7nH (Toko LL1005-FHL4N7S)	15nH (Toko LL1005-FHL15NS)
L2	0402	18.0nH (Coilcraft 0402CS-18NXJBW)	27.0nH (Toko LL1005-FHL27NS)	18.0nH (Toko LL1005-FHL18NS)	15nH (Toko LL1005-FHL15NS)
L3	0402	Not Placed	Not Placed	6.8nH (Toko LL1005-FHL6N8S)	Not Placed
C1	0402	2.4pF (Rohm MCH155A024CK)	3.9pF (Rohm MCH155A3R9JK)	1.5pF (Rohm MCH155A1R5CK)	3pF
C2	0402	100pF (Rohm MCH155A101JK)	100pF (Rohm MCH155A101JK)	100pF (Rohm MCH155A101JK)	2.2pF (Rohm MCH155A2R2CK)
C3	0402	5.6pF (Rohm MCH155A056CK)	5.6pF (Rohm MCH155A5R6CK)	5.6pF (Rohm MCH155A5R6CK)	2.2pF (Rohm MCH155A4R7CK)
C4	0402	100pF (Rohm MCH155A101JK)	100pF (Rohm MCH155A101JK)	100pF (Rohm MCH155A101JK)	33pF
C5	0402	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)
C6	0402	9pF (Rohm MCH155A090DK)	9.0pF (Rohm MCH155A090DK)	9.0pF (Rohm MCH155A090DK)	33pF
C7	0402	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)	0.1uF (Kyocera CM05X5R104K10AH)
C8					10nF
R1	0402	91 $\Omega$ (Rohm MCR01MZSJ910)	56 $\Omega$ (Rohm MCR0 MZSJ560)	300 $\Omega$ (Rohm MCR01MZSJ301)	100R (Rohm MCR01MZS101)
R2					620R (Rohm MCR01MZ621)
R3					56R (Rohm MCR0MZSJ560)
Rbias	0402	620 $\Omega$ (Rohm MCR01MZS621)	620 $\Omega$ (Rohm MCR01MZS621)	620 $\Omega$ (Rohm MCR01MZS621)	

## Load pull test set up

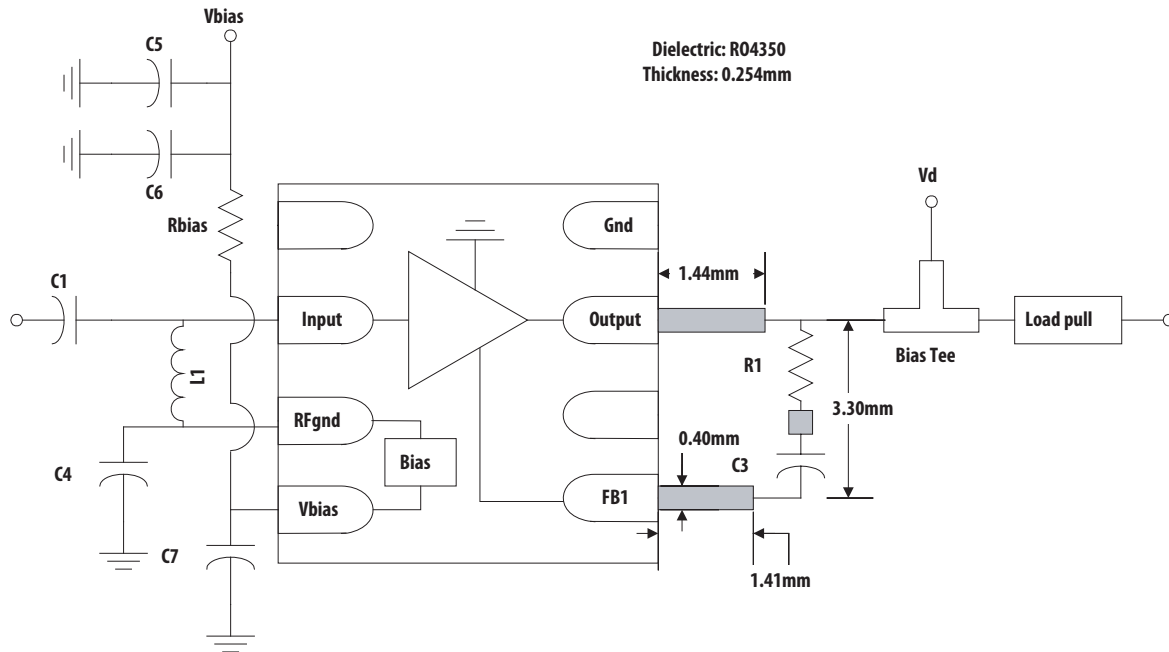


Figure 33. Test setup for load pull data

The input port is matched for good NF and IRL. Because of the high reverse isolation, any change on the output port has a minimum change on the input port. Therefore, only the output port is tuned for the maximum OIP3. R1 is varied for different level of gain Test condition for the OIP3: -20dBm at 900MHz  $\pm$ 5MHz.

## Measured results

Test condition: 4V/54mA, 900MHz

Refer to Table 1, List 1 for SMT component value and description, unless otherwise stated.

Resistor, R1	$\Gamma$	OIP3 (max)
91ohm	0.81 < 44.3o	+39.0dBm
56ohm	0.65 < 94.2o	+34.2dBm
560ohm	0.38 < 85.2o	+38.7dBm

### Fixed Load Pull

Freq = 0.9000 GHz

Ip3 max = 38.99 dBm  
at 0.8053 < 44.31  
10 contours, 1.00 dBm step  
(29.00 to 38.00 dBm)

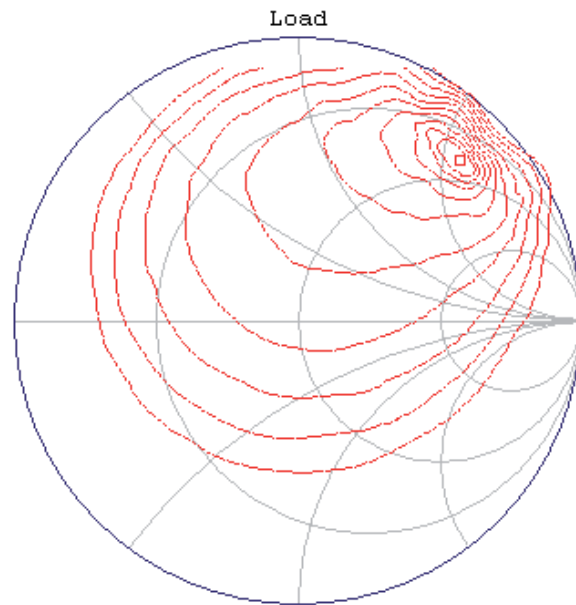


Figure 34. Load pull contour plot for R1=91ohm

Fixed Load Pull  
Freq = 0.9000 GHz

Ip3 max = 34.23 dBm  
at 0.6500< 94.18  
10 contours, 1.00 dBm step  
(25.00 to 34.00 dBm)

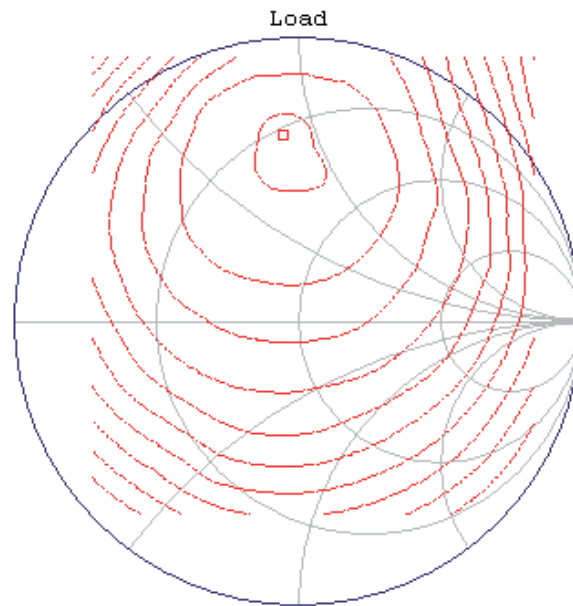


Figure 35. Load pull contour plot for R1=56ohm

Fixed Load Pull  
Freq = 0.9000 GHz

Ip3 max = 38.70 dBm  
at 0.3845< 85.21  
10 contours, 1.00 dBm step  
(29.00 to 38.00 dBm)

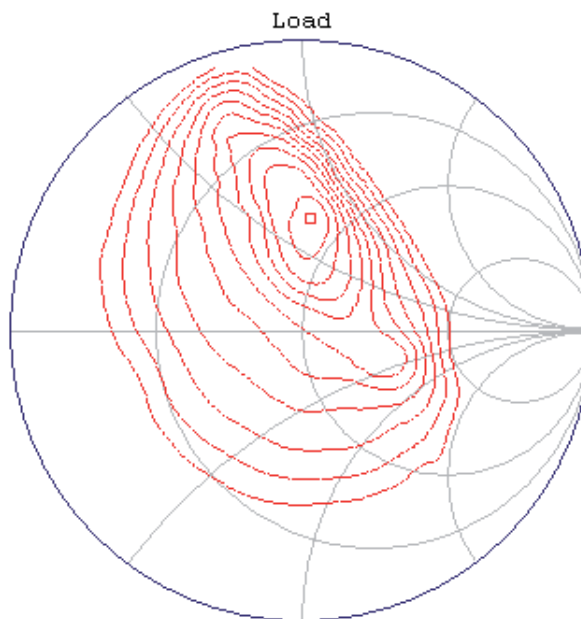


Figure 36. Load pull contour plot for R1=560ohm



**MGA631P8 Typical Scattering Parameters, Vd=4V, Id=54mA, R1=56ohm**

Freq (GHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.94	-11.1	23.02	155.7	0.003	47.9	0.63	-24.7
0.5	0.63	-25.3	10.46	117.6	0.011	48.7	0.37	-81.7
1.0	0.53	-23.4	5.38	110.3	0.014	37.1	0.30	-112.7
1.5	0.52	-25.0	3.59	113.4	0.015	39.5	0.27	-128.5
1.9	0.53	-28.7	2.92	118.6	0.016	35.0	0.27	-137.7
2.0	0.53	-29.7	2.76	118.7	0.016	35.3	0.27	-134.7
2.5	0.53	-34.8	2.45	122.6	0.015	34.0	0.29	-140.7
3.0	0.54	-40.0	2.09	125.5	0.015	34.9	0.33	-145.0
3.5	0.55	-44.7	1.93	128.3	0.016	36.7	0.38	-153.5
4.0	0.56	-48.5	1.71	130.9	0.017	32.4	0.44	-164.3
5.0	0.58	-56.9	1.53	132.4	0.022	28.7	0.48	167.6
6.0	0.61	-66.0	1.38	133.4	0.034	22.0	0.46	133.6
7.0	0.64	-77.7	1.33	132.4	0.053	11.5	0.39	87.3
8.0	0.71	-97.8	1.45	118.4	0.111	-8.7	0.28	1.6

**MGA631P8 Typical Scattering Parameters, Vd=4V, Id=54mA, R1=91ohm**

Freq (GHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.94	-10.9	22.91	156.2	0.008	65.8	0.61	-25.3
0.5	0.64	-24.8	10.73	121.3	0.009	44.3	0.33	-70.4
1.0	0.54	-23.8	6.02	113.0	0.012	34.1	0.28	-89.1
1.5	0.53	-26.2	4.14	112.0	0.013	37.2	0.30	-103.4
1.9	0.52	-29.4	3.28	114.2	0.014	33.7	0.34	-115.7
2.0	0.53	-30.3	3.09	113.4	0.013	36.8	0.35	-116.6
2.5	0.53	-35.4	2.64	116.1	0.013	34.3	0.40	-130.4
3.0	0.53	-40.0	2.12	118.9	0.013	35.8	0.44	-141.6
3.5	0.54	-44.2	1.90	122.7	0.014	36.4	0.47	-153.9
4.0	0.55	-48.2	1.64	126.5	0.015	34.4	0.49	-166.2
5.0	0.58	-56.5	1.47	130.3	0.022	30.5	0.51	165.7
6.0	0.61	-65.8	1.34	132.4	0.033	23.2	0.48	132.7
7.0	0.64	-77.6	1.30	132.0	0.052	13.4	0.40	88.2
8.0	0.71	-97.5	1.42	118.0	0.111	-7.9	0.29	5.2

Notes:

1. S-parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 35 shows the input and output reference plane.

**MGA631P8 Typical Scattering Parameters, Vd=4V, Id=54mA, R1=300ohm**

Freq (GHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.93	-10.1	22.64	158.5	0.003	28.6	0.59	-18.6
0.5	0.67	-24.0	12.70	126.7	0.006	37.0	0.42	-34.6
1.0	0.57	-26.6	7.55	112.4	0.007	36.2	0.47	-59.4
1.5	0.53	-28.5	5.09	106.7	0.008	43.5	0.52	-83.0
1.9	0.52	-31.7	3.85	106.4	0.008	45.9	0.54	-99.8
2.0	0.52	-32.4	3.59	104.9	0.009	47.1	0.55	-103.5
2.5	0.52	-36.7	3.00	107.1	0.009	40.4	0.57	-121.8
3.0	0.53	-40.6	2.26	108.9	0.010	39.0	0.59	-136.7
3.5	0.54	-45.0	1.96	113.2	0.011	43.6	0.60	-151.2
4.0	0.55	-48.5	1.64	118.1	0.013	36.8	0.61	-165.0
5.0	0.57	-56.5	1.42	123.5	0.020	27.8	0.57	166.4
6.0	0.60	-65.8	1.29	127.3	0.033	19.7	0.52	134.9
7.0	0.64	-77.8	1.27	127.1	0.052	10.9	0.41	93.3
8.0	0.71	-99.2	1.37	112.5	0.108	-7.4	0.26	14.4

**MGA631P8 Typical Scattering Parameters, Vd=4V, Id=54mA, R1=560ohm**

Freq (GHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.93	-9.5	22.87	160.4	0.002	61.7	0.60	-13.3
0.5	0.69	-24.3	13.48	126.6	0.004	44.7	0.50	-31.3
1.0	0.56	-26.9	7.90	111.2	0.005	44.5	0.54	-57.9
1.5	0.53	-29.0	5.29	105.1	0.007	48.3	0.56	-81.7
1.9	0.51	-31.5	3.97	104.8	0.007	48.9	0.59	-98.7
2.0	0.52	-32.4	3.70	103.0	0.008	46.4	0.60	-102.5
2.5	0.52	-36.4	3.08	105.3	0.008	45.0	0.62	-120.9
3.0	0.53	-40.6	2.31	106.9	0.010	42.6	0.62	-136.1
3.5	0.54	-44.6	2.00	111.5	0.011	40.1	0.63	-150.5
4.0	0.55	-48.1	1.65	116.2	0.013	36.6	0.63	-164.1
5.0	0.57	-56.6	1.43	121.6	0.020	26.9	0.60	167.5
6.0	0.60	-65.6	1.30	125.5	0.033	19.9	0.53	136.4
7.0	0.64	-77.0	1.29	125.5	0.052	9.8	0.40	95.6
8.0	0.71	-98.0	1.40	109.4	0.107	-8.9	0.22	17.0

Notes:

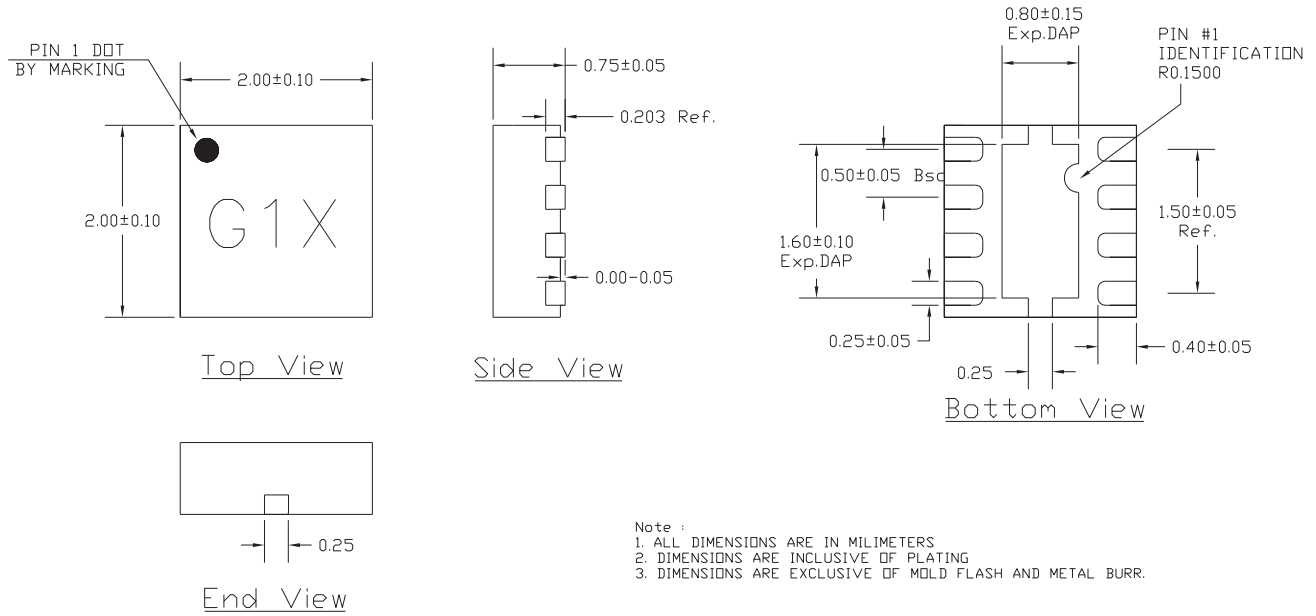
1. S-parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 35 shows the input and output reference plane.



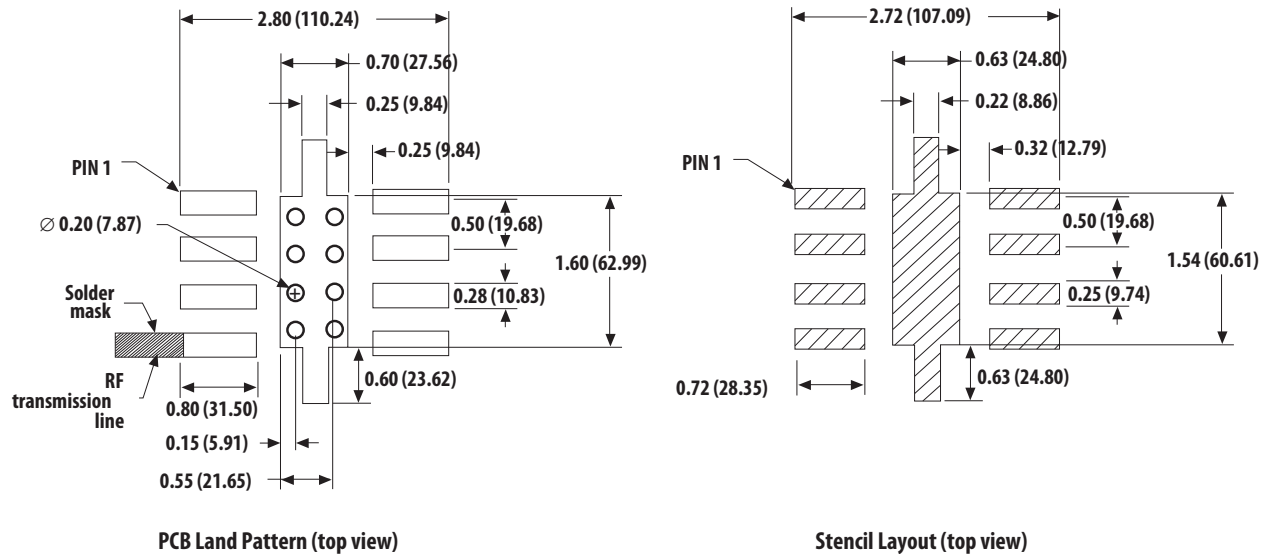
## Ordering Information

Part Number	No. of Devices	Container
MGA-631P8-TR1G	3000	7" Reel
MGA-631P8-TR2G	10000	13" Reel
MGA-631P8-BLKG	100	antistatic bag

## TSLP2X2 Package Dimension

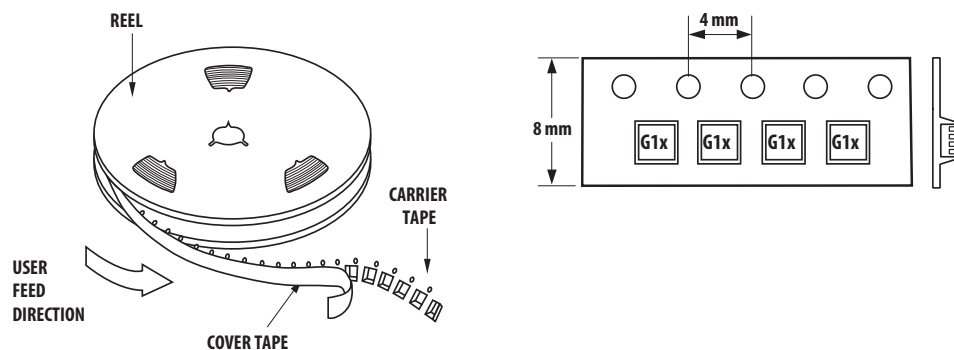


## PCB Land Pattern and Stencil Design

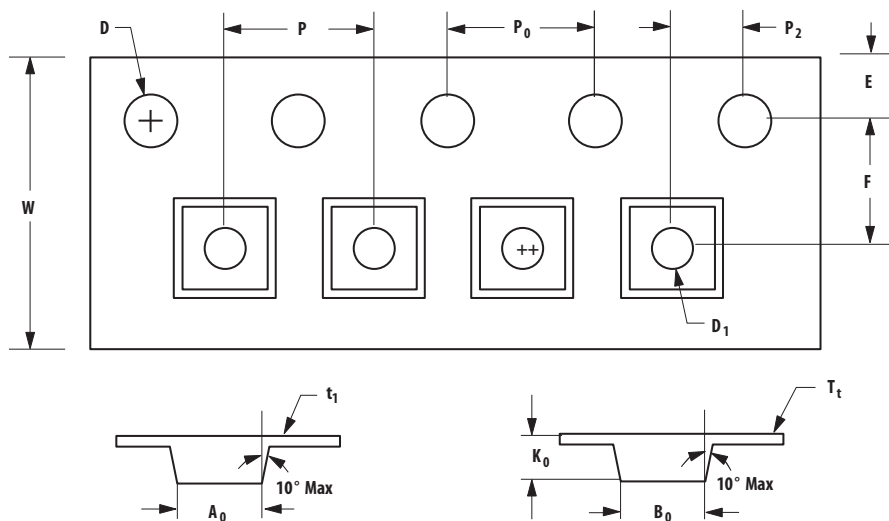


All dimensions are in millimeters (mils)  
 Note: 1 mil = 1/1000 inch

## Device Orientation



## Tape Dimensions



DESCRIPTION		SYMBOL	SIZE (mm)	SIZE (inches)
CAVITY	LENGTH	A <sub>0</sub>	2.30 ± 0.05	0.091 ± 0.004
	WIDTH	B <sub>0</sub>	2.30 ± 0.05	0.091 ± 0.004
	DEPTH	K <sub>0</sub>	1.00 ± 0.05	0.039 ± 0.002
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D <sub>1</sub>	1.00 ± 0.25	0.039 ± 0.002
	PERFORATION	DIAMETER	D	1.50 ± 0.10
	PITCH	P <sub>0</sub>	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	0.069 ± 0.004
CARRIER TAPE	WIDTH	W	8.00 ± 0.30	0.315 ± 0.012
	THICKNESS	t <sub>1</sub>	8.00 ± 0.10 0.254 ± 0.02	0.315 ± 0.004 0.010 ± 0.0008
COVER TAPE	WIDTH	C	5.4 ± 0.10	0.205 ± 0.004
	TAPE THICKNESS	T <sub>t</sub>	0.062 ± 0.001	0.0025 ± 0.0004
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P <sub>2</sub>	2.00 ± 0.05	0.079 ± 0.002

For product information and a complete list of distributors, please go to our web site: [www.avagotech.com](http://www.avagotech.com)

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